NSN 5962-01-352-0113

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-352-0113

_		T		D
u	perating	ı embui	rature	Range:

-55.0/+125.0 degrees celsius

Features Provided:

High performance and schottky and bipolar and 3-state output

Inclosure Configuration:

Dual-in-line

Memory Device Type:

Prom

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0